

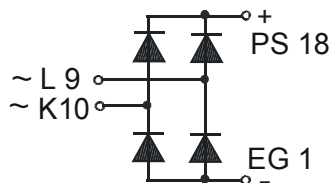
Single Phase Rectifier Bridge

PSB 88

$I_{dAV} = 92 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

Preliminary Data Sheet

V_{RSM} V_{DSM} (V)	V_{RRM} V_{DRM} (V)	Type
800	800	PSB 88/08
1200	1200	PSB 88/12
1400	1400	PSB 88/14
1600	1600	PSB 88/16



Symbol	Test Conditions	Maximum Ratings
I_{dAVM}	$T_C = 100^\circ\text{C}$, (per module)	92 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	900 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	990 A
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	770 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	850 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	4050 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	4050 A ² s
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	2950 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	2950 A ² s
T_{VJ}		-40... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40... + 125 °C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V~
M_g	Mounting torque (M4)	1.5 - 2.0 Nm
Weight	typ.	22 g

Features

- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- UL registered, E 148688

Applications

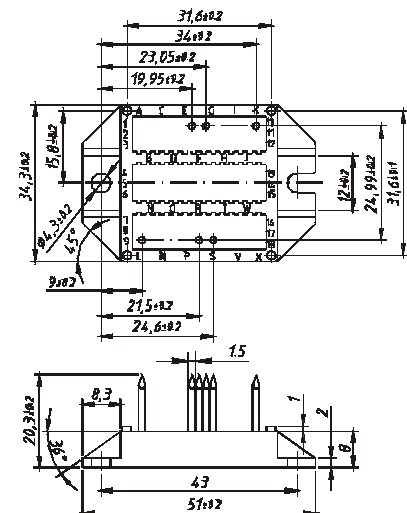
- Supplies for DC power equipment
- Input rectifier for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density
- Small and light weight

Package style and outline

Dimensions in mm (1mm = 0.0394")



Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}$, $T_{VJ} = 25^\circ\text{C}$	$\leq 0.5 \text{ mA}$
	$V_R = V_{RRM}$, $T_{VJ} = T_{VJM}$	$\leq 5 \text{ mA}$
V_F	$I_F = 200 \text{ A}$, $T_{VJ} = 25^\circ\text{C}$	$\leq 1.75 \text{ V}$
V_{TO}	For power-loss calculations only	0.8 V
r_T		4.0 mΩ
R_{thJC}	per diode; DC current	0.85 K/W
	per module	0.212 K/W
R_{thJK}	per diode; DC current	1.15 K/W
	per module	0.288 K/W
d_s	Creeping distance on surface	11.2 mm
d_A	Creeping distance in air	9.7 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 refer to a single diode unless otherwise stated